

DIGITAL OUTPUT PHOTO REFLECTOR

■ GENERAL DESCRIPTION

The NJL5802K is thin package digital output type photo reflector which consist of New JRC original designed one chip photo receiving IC and high output LED.

■ FEATURES

- Normally off type
- With schmitt trigger circuit
- TTL Compatible
- Built-in visible light cut-off filter.

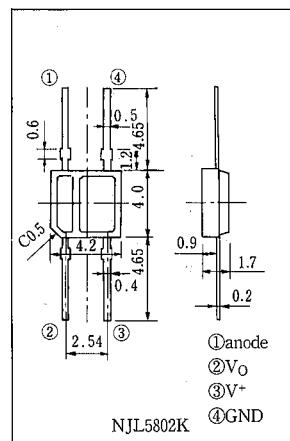
■ APPLICATIONS

- Tape end sensor
- Reel rotation sensor
- Paper detector, Paper end sensor
- Bar code reader
- Sensor of FDD, Robot, manufacturing installation, etc.

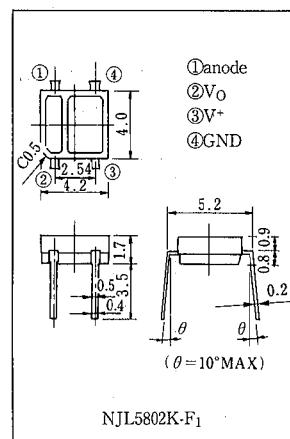
■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

PARAMETER	SYMBOL	RATINGS	UNIT
Emitter			
Forward Current (Continuous)	I _F	50	mA
Reverse Voltage (Continuous)	V _R	6	V
Power Dissipation	P _D	75	mW
Detector			
Supply Voltage	V ⁺	16	V
High Level Output Voltage	V _{OH}	16	V
Low Level Output Current	I _{OL}	50	mA
Power Dissipation	P _O	110	mW
Coupler			
Total Power Dissipation	P _{tot}	130	mW
Operating Temperature	T _{opr}	-20 ~ +85	°C
Storage Temperature	T _{sig}	-30 ~ +100	°C
Soldering Temperature	T _{sot}	260	°C
		(5sec. 1.5mm from body)	

■ OUTLINE (typ.) Unit: mm

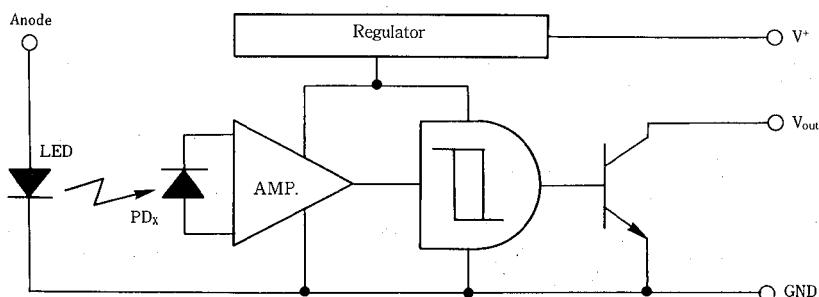


NJL5802K



NJL5802K-F1

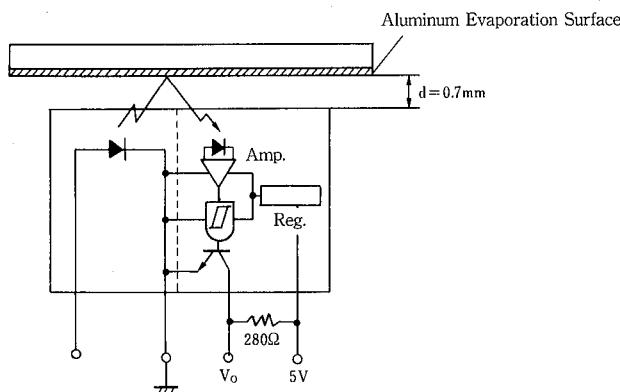
■ BLOCK DIAGRAM



■ ELECTRO-OPTICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

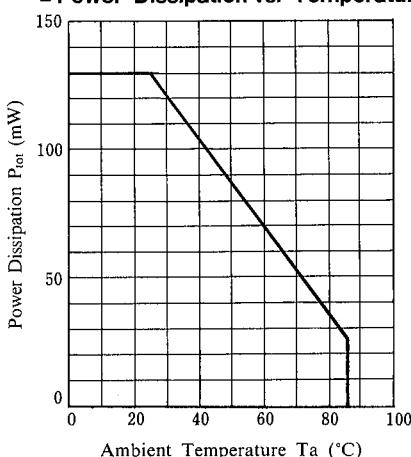
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Emitter						
Forward Voltage	V_F	$I_F = 10\text{mA}$	—	1.1	1.3	V
Reverse Current	I_R	$V_R = 6\text{V}$	—	—	1.0	μA
Capacitance	C_t	$V_R = 0\text{V}, f = 1\text{MHz}$	—	25	—	pF
Detector						
Supply Voltage Range	V^+		3.5	—	15	V
Low Level Output Voltage	V_{OL}	$I_{OL} = 16\text{mA}, V^+ = 5\text{V}, I_F = 10\text{mA}, d = 0.7\text{mm}$	—	0.2	0.5	V
High Level Output Current	I_{OH}	$V_O = V^+ = 15\text{V}, I_F = 0\text{mA}$	—	—	100	μA
Low Level Supply Current	I_{CL}	$V^+ = 5\text{V}, I_F = 10\text{mA}, d = 0.7\text{mm}$	—	3	10	mA
High Level Supply Current	I_{CH}	$V^+ = 5\text{V}, I_F = 0\text{mA}$	—	4.5	10	mA
Coupled						
H \rightarrow L Threshold Input Current	I_{FHL}	$V^+ = 5\text{V}, R_L = 280\Omega, d = 0.7\text{mm}$	—	—	10	mA
Hysteresis	I_{FLH}/I_{FHL}	$V^+ = 5\text{V}, R_L = 280\Omega, d = 0.7\text{mm}$	—	0.8	—	—
H \rightarrow L Delay Time	t_{PHL}	$V^+ = 5\text{V}, R_L = 280\Omega, I_F = 10\text{mA}, d = 0.7\text{mm}$	—	10	—	μs
L \rightarrow H Delay Time	t_{PLH}	$V^+ = 5\text{V}, R_L = 280\Omega, I_F = 10\text{mA}, d = 0.7\text{mm}$	—	5	—	μs
Fall Time	t_f	$V^+ = 5\text{V}, R_L = 280\Omega, I_F = 10\text{mA}, d = 0.7\text{mm}$	—	0.1	—	μs
Rise Time	t_r	$V^+ = 5\text{V}, R_L = 280\Omega, I_F = 10\text{mA}, d = 0.7\text{mm}$	—	0.1	—	μs

■ MEASURING SPECIFICATION FOR THRESHOLD INPUT CURRENT

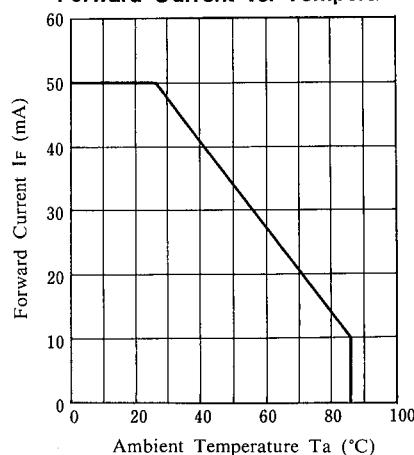


■ MAXIMUM RATING CURVES

■ Power Dissipation vs. Temperature



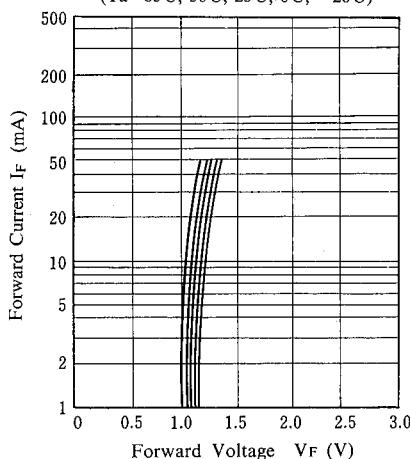
Forward Current vs. Temperature



■ TYPICAL CHARACTERISTICS

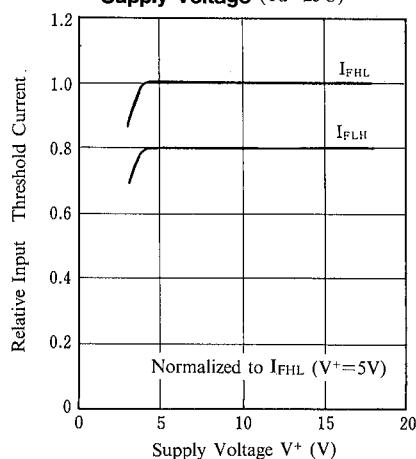
Forward Current vs. Forward Voltage

(Ta=85°C, 50°C, 25°C, 0°C, -20°C)

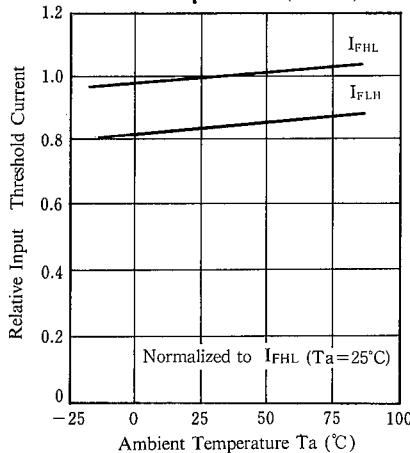


Input Threshold Current vs.

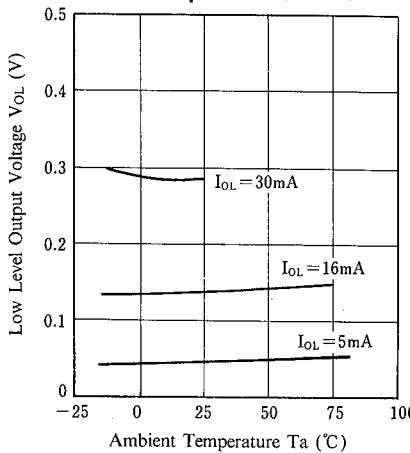
Supply Voltage (Ta=25°C)



Input Threshold Current vs. Temperature (V+=5V)

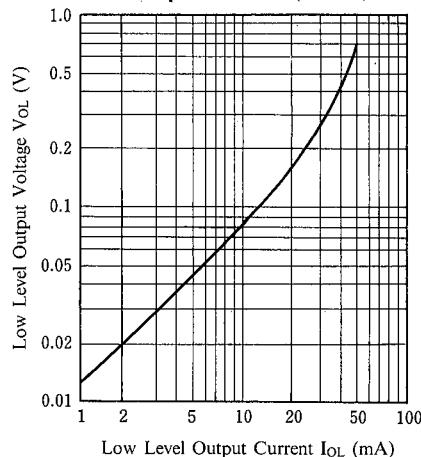


Low Level Output Voltage vs. Temperature (V+=5V)



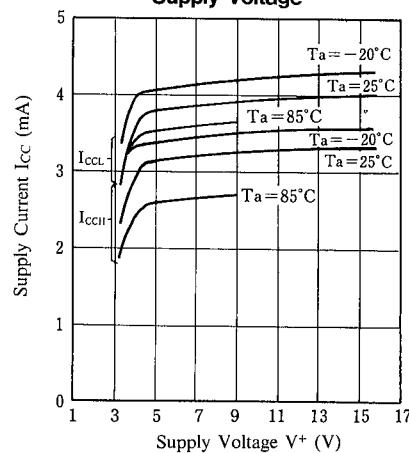
Low Level Output Voltage vs.

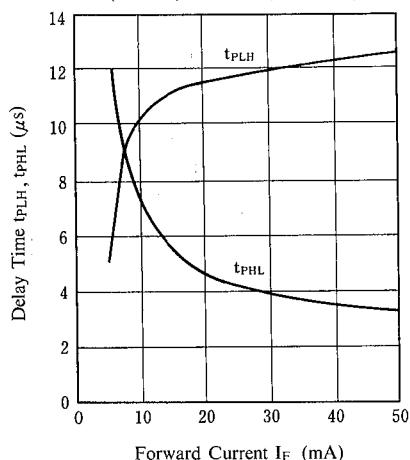
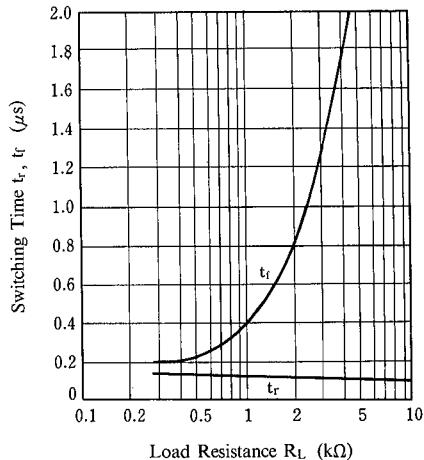
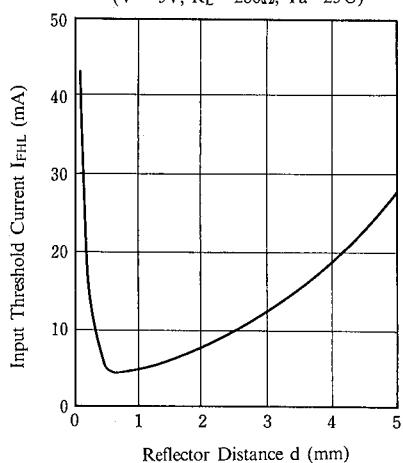
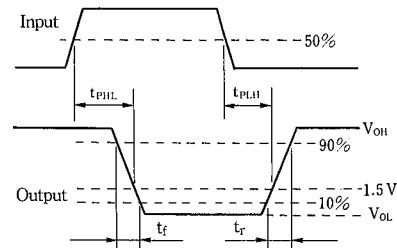
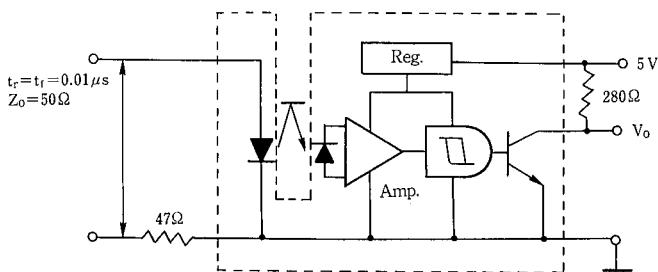
Low Level Output Current (V+=5V, Ta=25°C)



Supply Current vs.

Supply Voltage



Delay Time vs. Forward Current(V⁺=5V, R_L=280Ω, Ta=25°C)**Switching Time vs. Resistance**(V⁺=5V, I_F=10mA, Ta=25°C)**Input Threshold Current vs. Distance**(V⁺=5V, R_L=280Ω, Ta=25°C)**Measuring Circuit for Response Time**

NJL5802K

MEMO

[CAUTION]

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西安分公司：西安高新区 20 所(中国电子科技集团导航技术研究所)

西安劳动南路 88 号电子商城二楼 D23 号

TEL：029-81022619 13072977981 FAX:029-88789382